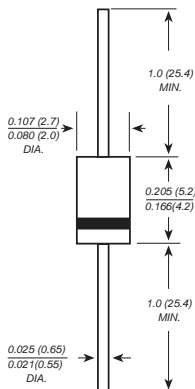


# 1N5817S THRU 1N5819S

## SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 40Volts    Forward Current - 1.0 Ampere

A-405



Dimensions in inches and (millimeters)

### FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Guardring for overvoltage protection
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ High temperature soldering guaranteed:  
260°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC A-405 molded plastic body

**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.008 ounce, 0.23 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for current capacitive load derate by 20%.

	SYMBOLS	1N5817S	1N5818S	1N5819S	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	V
Maximum RMS voltage	$V_{RMS}$	14	21	28	V
Maximum DC blocking voltage	$V_{DC}$	20	30	40	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_L=90^\circ\text{C}$	$I_{AV}$	1.0			A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	25.0			A
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.450	0.550	0.600	V
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	0.5 10.0			mA
Typical junction capacitance (NOTE 1)	$C_J$	110.0			pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0			$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +125			$^\circ\text{C}$

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

# RATINGS AND CHARACTERISTIC CURVES 1N5817S THRU 1N5819S

FIG. 1- FORWARD CURRENT DERATING CURVE

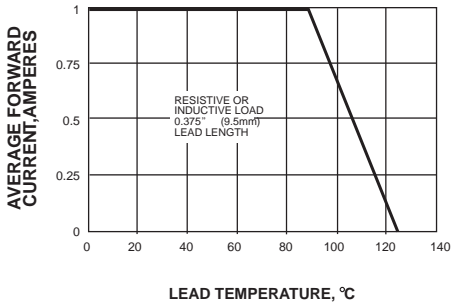


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

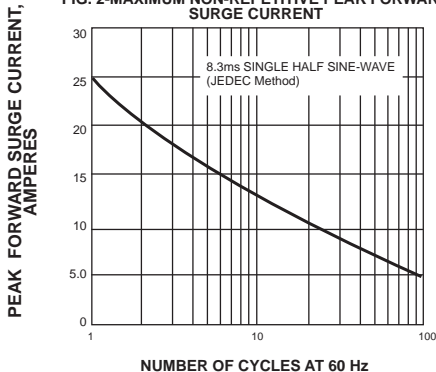


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

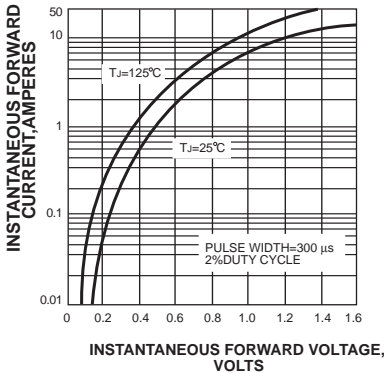


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

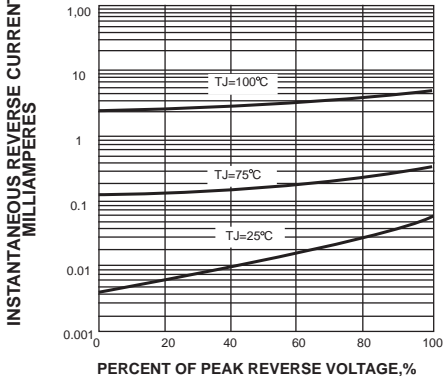


FIG. 5-TYPICAL JUNCTION CAPACITANCE

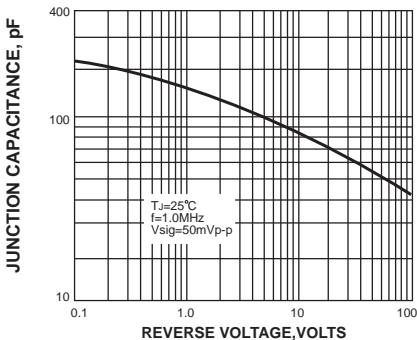


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

